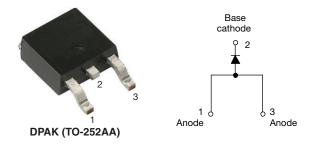
Vishay Semiconductors

High Voltage Surface Mountable Input Rectifier Diode, 8 A



www.vishay.com

PRIMARY CHARACTERISTICS		
I _{F(AV)}	8 A	
V _R	1200 V	
V _F at I _F	1.1 V	
I _{FSM}	150 A	
T _J max.	150 °C	
Package	DPAK (TO-252AA)	
Circuit configuration	Single	

FEATURES

- Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Flexible solution for reliable AC power rectification
- $\bullet\,$ High surge, low V_F rugged blocking diode for DC charging stations
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- · On-board and off-board EV / HEV battery chargers
- Renewable energy inverters

DESCRIPTION

The VS-8EWS12SLHM3 rectifier high voltage series has been optimized for very low forward voltage drop, with moderate leakage.

The **high reverse voltage** range available allows design of input stage primary rectification with **outstanding voltage surge** capability.

OUTPUT CURRENT IN TYPICAL APPLICATIONS				
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS	
NEMA FR-4 or G10 glass fabric-based epoxy with 4 oz. (140 $\mu m)$ copper	1.2	1.6		
Aluminum IMS, R _{thCA} = 15 °C/W	2.5	2.8	A	
Aluminum IMS with heatsink, $R_{thCA} = 5 \text{ °C/W}$	5.5	6.5		

Note

• $T_A = 55 \text{ °C}, T_J = 125 \text{ °C}, \text{ footprint } 300 \text{ mm}^2$

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
I _{F(AV)}	Sinusoidal waveform	8	А
V _{RRM}		1200	V
I _{FSM}		150	A
V _F	8 A, T _J = 25 °C	1.10	V
TJ		-55 to +150	°C

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA
VS-8EWS12SLHM3	1200	1300	0.50

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COMPLIANT HALOGEN



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ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	I _{F(AV)}	T_C = 105 °C, 180° conduction half sine wave	8	
Maximum peak one cycle	1	10 ms sine pulse, rated V _{RRM} applied	125	А
non-repetitive surge current	I _{FSM}	10 ms sine pulse, no voltage reapplied	150	
Maximum I ² t for fusing I ² t	l ² t	10 ms sine pulse, rated V _{RRM} applied	78	A ² s
Maximum - t for fusing	1-1	10 ms sine pulse, no voltage reapplied	110	A-5
Maximum I ² √t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	1100	A²√s

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
Maximum forward voltage drop	V _{FM}	8 A, T _J = 25 °C		1.1	V
Forward slope resistance	r _t	T.I = 150 °C		20	mΩ
Threshold voltage	V _{F(TO)}	1j = 150°C		0.82	V
Maximum reverse leakage current	1	$T_J = 25 \text{ °C}$ $V_B = \text{rated } V_{BBM}$	\mathcal{V}_{-} roted \mathcal{V}_{-}	0.05	mA
Maximum reverse leakage current	T _J = 150 °C	$v_{\rm R} = rate v_{\rm RRM}$	0.50	ШA	

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	°C/W
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		62	C/W
Approvimate weight			1	g
Approximate weight			0.03	oz.
Marking device		Case style DPAK (TO-252AA)	8EWS	12SH

Note

(1) When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W

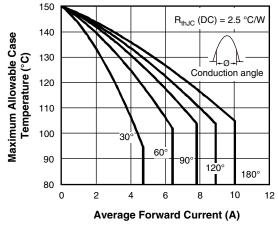


Fig. 1 - Current Rating Characteristics

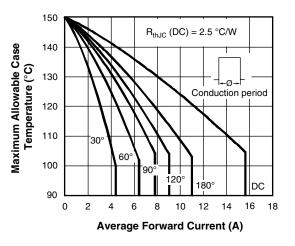


Fig. 2 - Current Rating Characteristics

2

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VS-8EWS12SLHM3

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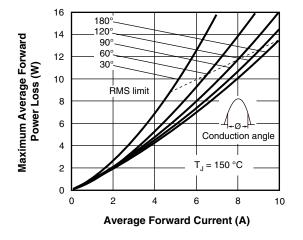


Fig. 3 - Forward Power Loss Characteristics

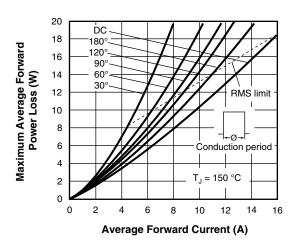
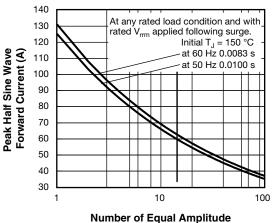


Fig. 4 - Forward Power Loss Characteristics



Half Cycle Current Pulses (N)

Fig. 5 - Maximum Non-Repetitive Surge Current

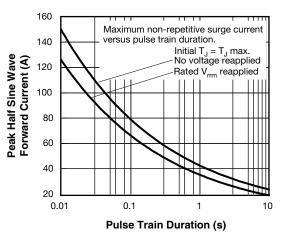
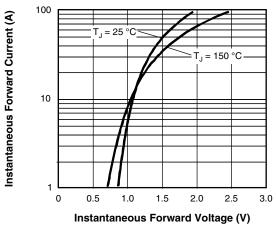


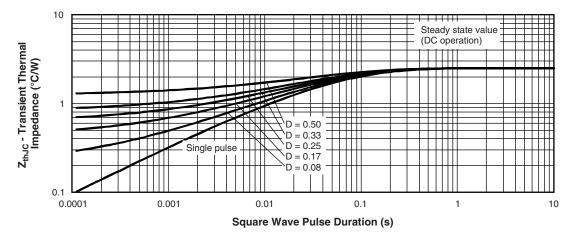
Fig. 6 - Maximum Non-Repetitive Surge Current





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Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE Device code VS-S S 8 Ε w 12 L н М3 (5)2) (3) (6)7 1 4 8 9 (10)Vishay Semiconductors product 2 Current rating (8 = 8 A)-3 Circuit configuration: E = single 4 Package: _ W = DPAK (TO-252AA) 5 Type of silicon: _ S = standard recovery rectifier Voltage code x 100 = V_{RRM} — 12 = 1200 V 6 -S = surface mountable 7 -8 L = tape and reel (left oriented), for different orientation contact factory _ 9 H = AEC-Q101 qualified -10 Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)				
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION	
VS-8EWS12SLHM3	3000	3000	13" diameter reel	

LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95519	
Part marking information	www.vishay.com/doc?95518	
Packaging information	www.vishay.com/doc?96495	
SPICE model	www.vishay.com/doc?96668	

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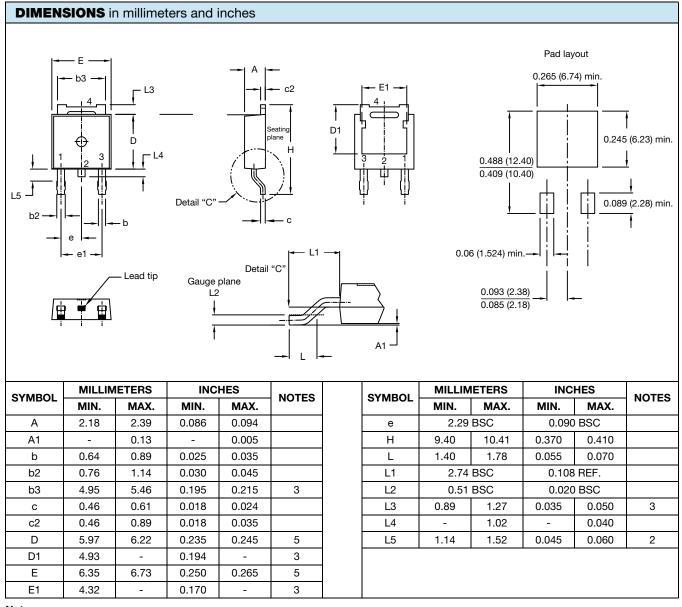
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Outline Dimensions



Vishay Semiconductors

DPAK (TO-252AA)



Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Dimensions D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁵⁾ Outline conforms to JEDEC[®] outline TO-252AA, except for D1 dimension



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